

TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type

2SK1771

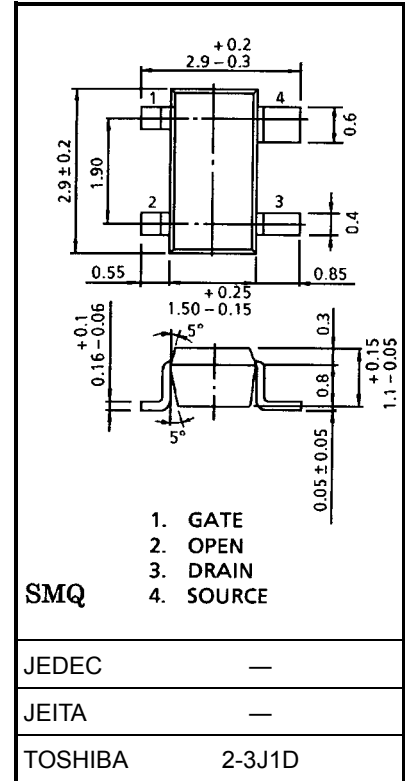
FM Tuner, VHF RF Amplifier Applications

Unit: mm

- Superior inter modulation performance.
- Low noise figure: NF = 1.0dB (typ.)

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V _{DS}	12.5	V
Gate-source voltage	V _{GS}	±8	V
Drain current	I _D	30	mA
Drain power dissipation	P _D	150	mW
Channel temperature	T _{ch}	125	°C
Storage temperature range	T _{stg}	-55~125	°C



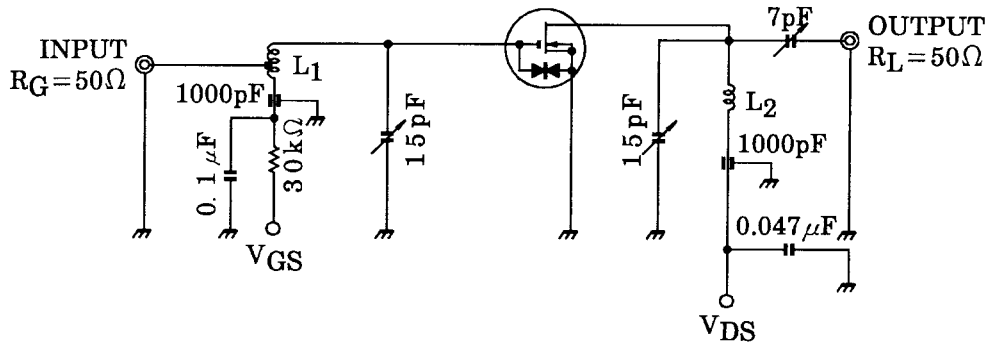
- SMQ
1. GATE
 2. OPEN
 3. DRAIN
 4. SOURCE

JEDEC	—
JEITA	—
TOSHIBA	2-3J1D

Weight: 0.013 g (typ.)

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	I _{GSS}	V _{DS} = 0, V _{GS} = ±6 V	—	—	±50	nA
Drain-source voltage	V _{(BR)DSX}	V _{GS} = -4 V, I _D = 100 μA	12.5	—	—	V
Drain current	I _{DSS}	V _{DS} = 8 V, V _{GS} = 0	0	—	0.1	mA
Gate-source cut-off voltage	V _{GS(OFF)}	V _{DS} = 8 V, I _D = 100 μA	0.5	1.0	1.5	V
Forward transfer admittance	Y _{fs}	V _{DS} = 8 V, I _D = 10 mA, f = 1 kHz	—	15	20	mS
Input capacitance	C _{iss}	V _{DS} = 8 V, I _D = 10 mA, f = 1 MHz	2.9	3.5	4.1	pF
Reverse transfer capacitance	C _{rss}		—	0.3	0.8	pF
Power gain	G _{ps}	V _{DS} = 8 V, I _D = 10 mA, f = 100 MHz	18	23	28	dB
Noise figure	NF		—	1.0	2.2	dB

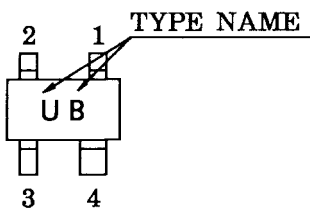


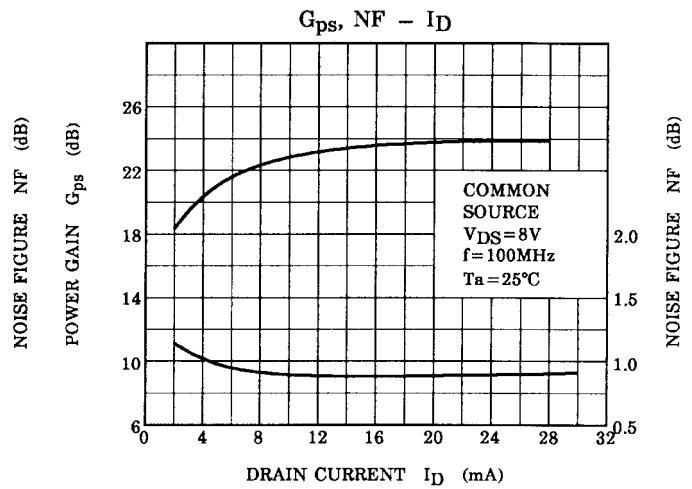
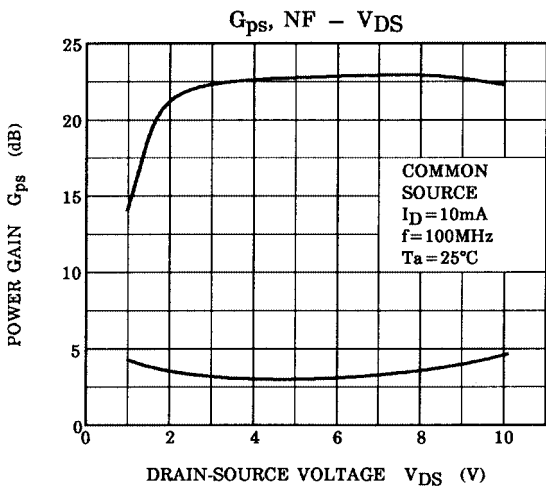
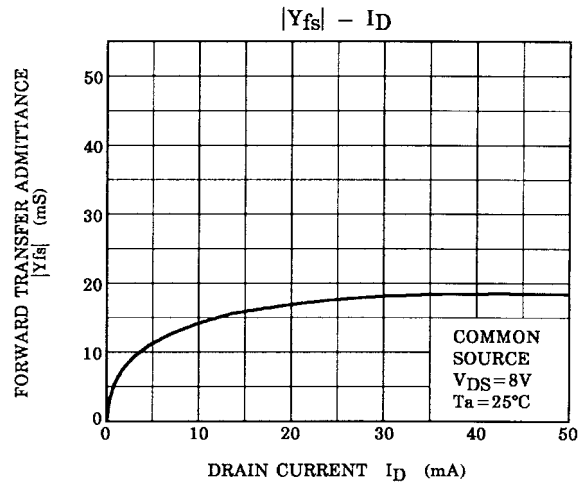
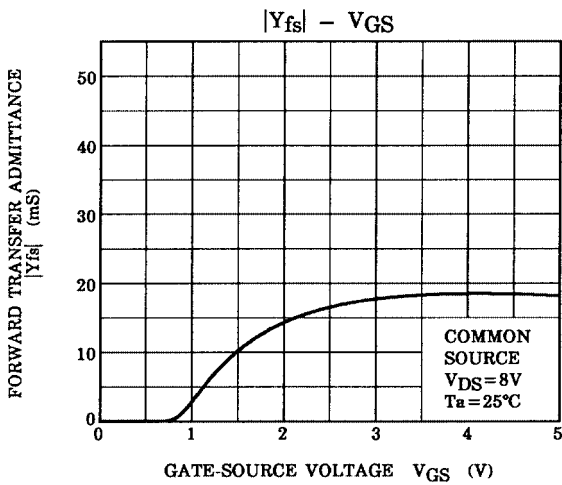
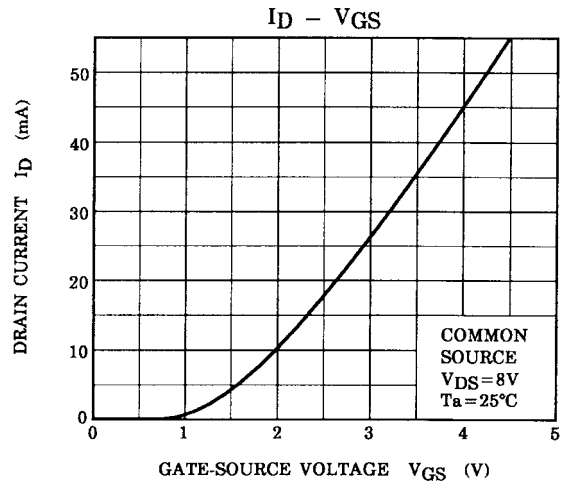
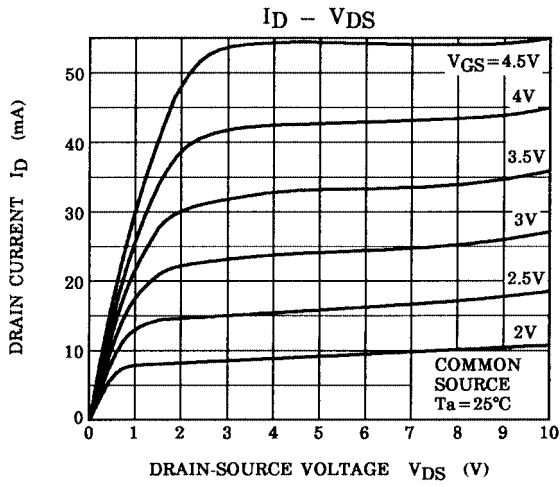
L1: 1.0 mmφ silver plated copper wire 4.0 T, 8 mmφ ID TAP at 1.0 T from coil end

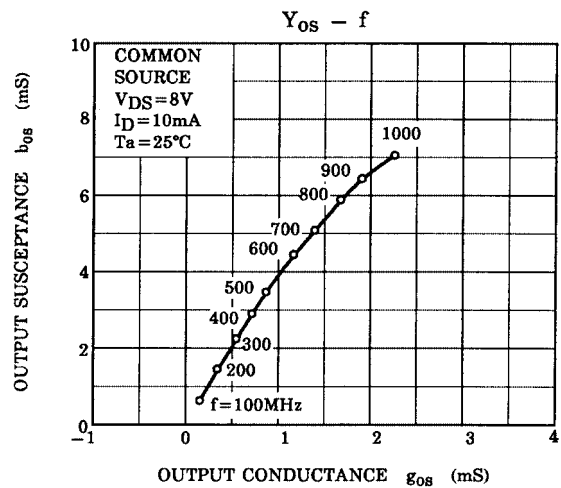
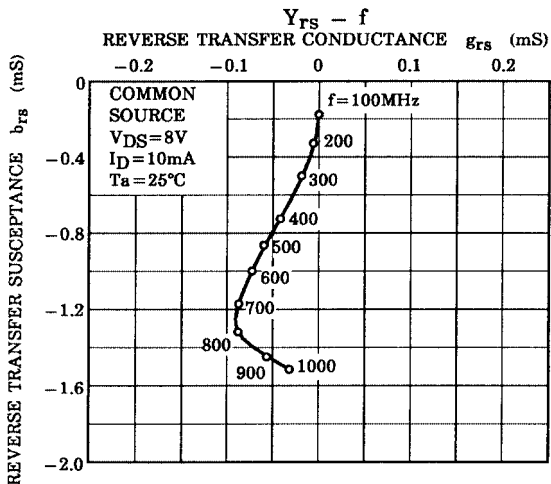
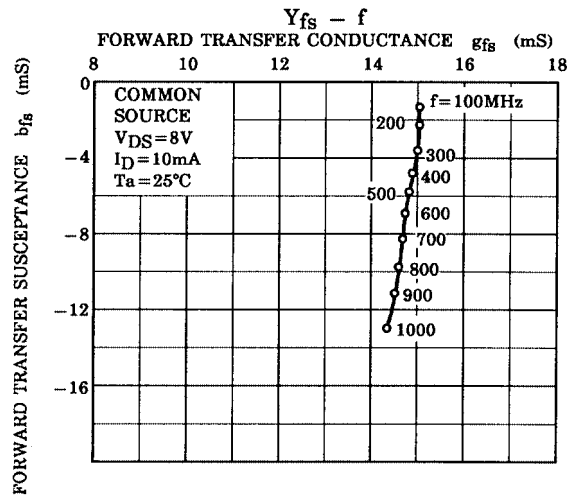
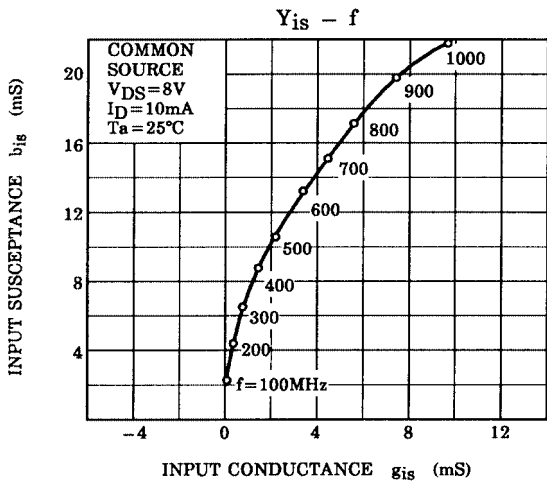
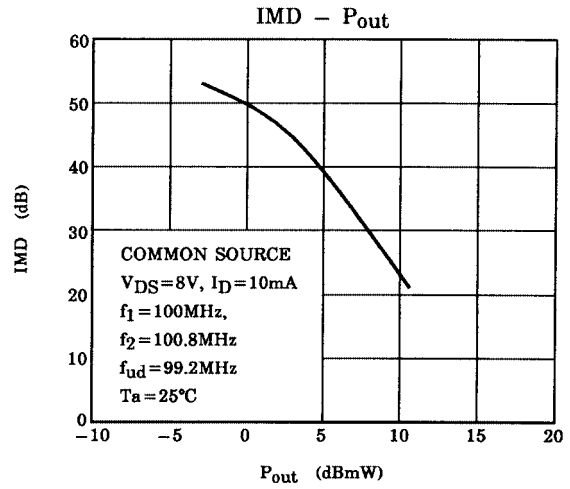
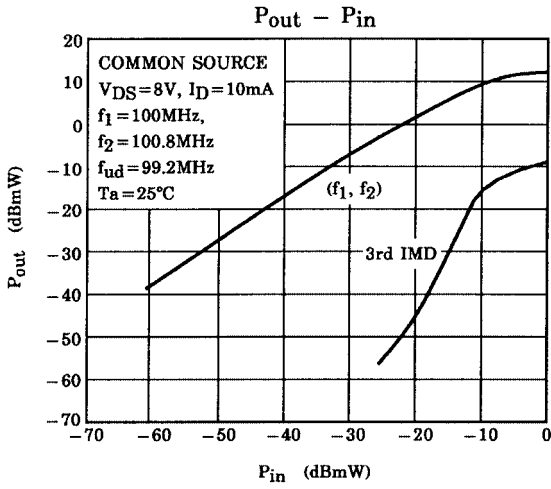
L2: 1.0 mmφ silver plated copper wire 3.0 T, 8 mmφ ID, 10 mm length

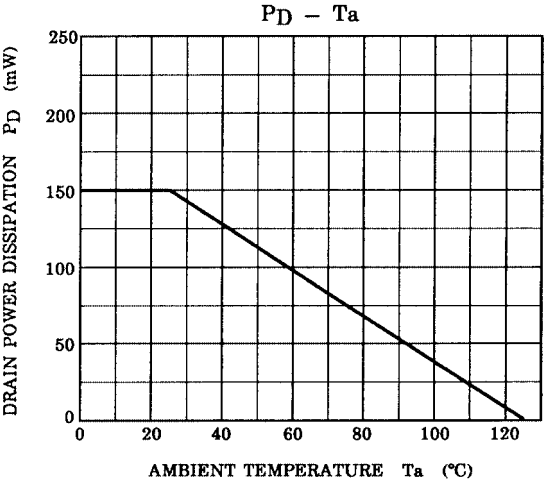
Figure 1 100 MHz G_{ps}, NF Test Circuit

Marking









RESTRICTIONS ON PRODUCT USE

000707EAA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.